

WHAT IS CLAIMED IS:

1 1. A memory comprising:
2 at least one array of memory elements;
3 a partition of the at least one array into a plurality of sub-arrays of the memory
4 elements;
5 an array configuration circuit for selectively putting the at least one array in
6 one of two operating configurations, the two operating configurations including:
7 a first operating configuration, in which the memory elements of the at least
8 one array are coupled one to another to form a monodimensional sequentially-
9 accessible memory, and
10 a second operating configuration, in which the memory elements in each sub-
11 array are coupled to one another so as to form an independent monodimensional
12 sequentially-accessible memory block, a data content of any memory element of the
13 sub-array being rotatable by shifts through the memory elements of the sub-array;
14 a sub-array selector, responsive to a first memory address, for selecting one
15 among the at least two sub-arrays according to the first memory address, the sub-
16 array selector enabling access to the selected sub-array; and
17 a memory element access circuit, responsive to a second memory address,
18 for enabling access to a prescribed memory element in the selected sub-array after a
19 prescribed number of shifts, depending on the second memory address, of the data
20 content of the memory elements in the selected sub-array.

1 2. The memory according to claim 1, in which said array configuration circuit
2 includes, for each sub-array of memory elements, an input selector associated with a
3 first memory element of the sub-array, for selectively feeding the first memory
4 element with either an output of a last memory element in an adjacent previous sub-
5 array, in the first operating configuration, or an output of a last memory element of
6 the sub-array, in the second operating configuration.

1 3. The memory according to claim 1, in which the first operating configuration
2 is a data storage configuration, in which the memory is put when data are to be
3 stored therein, and the second operating configuration is a data retrieval
4 configuration, in which the memory is put when data are to be retrieved therefrom.

1 4. The memory according to claim 3, in which in the second operating
2 configuration each sub-array provides a respective output data, the sub-array
3 selector selecting one sub-array output data out of the at least two output data
4 provided by the at least two sub-arrays, according to the first address.

1 5. The memory according to claim 4, in which said memory element access
2 circuit enables a transfer of the output data of the selected sub-array to a memory
3 output after a prescribed number of shifts of the data content of the memory
4 elements in the selected sub-array.

1 6. The memory according to claim 5, in which said memory element access
2 circuit includes a counter for counting the number of data content shifts, and a
3 coincidence detector detecting coincidence between a counter value and a value
4 representative of the second address, the coincidence detector enabling the transfer
5 of the output data of the selected sub-array to the memory output when the counter
6 value equals the value representative of the second address.

1 7. The memory according to claim 1, in which each memory element includes
2 at least one flip-flop.

1 8. A memory, comprising:
2 a plurality of memory locations each having a contents; and
3 a control circuit coupled to the memory locations and operable to,
4 allow random access to the memory locations during a first mode of
5 operation, and
6 allow sequential access to the contents of the memory locations via a
7 predetermined one of the memory locations during a second mode of
8 operation.

1 9. The memory of claim 8 wherein:
2 the first mode of operation comprises a read mode; and
3 the second mode of operation comprises a write mode.

1 10. The memory of claim 8 wherein:
2 the first mode of operation comprises a write mode; and
3 the second mode of operation comprises a read mode.

1 11. A memory, comprising:
2 an array of memory locations; and
3 a control circuit coupled to the array and operable to cause the array to
4 operate as
5 a random-access memory during a first mode of operation, and
6 a first-in-first-out memory during a second mode of operation.

1 12. The memory of claim 11 wherein:
2 the memory locations comprise a ring of serially coupled memory locations
3 each having a respective contents; and
4 during the first mode of operation, the control circuit is operable to,
5 receive a clock signal,
6 shift the contents of each respective memory location in the ring to a
7 respective next memory location in the ring once per cycle of the clock signal,
8 and
9 allow access to a predetermined one of the memory locations during a
10 predetermined cycle of the clock signal.

1 13. The memory of claim 11 wherein:
2 the memory locations comprise a ring of a number n of serially coupled
3 memory locations each having a respective contents; and
4 during the first mode of operation, the control circuit is operable to,
5 receive a clock signal,
6 shift the contents of each respective memory location in the ring to a
7 respective next memory location in the ring once per cycle of the clock signal
8 for n clock cycles, and
9 allow access to a predetermined one of the memory locations during a
10 predetermined cycle of the clock signal.

1 14. An electronic system, comprising:
2 a memory, comprising,
3 a plurality of memory locations each having a contents, and
4 a control circuit coupled to the memory locations and operable to,
5 allow random access to the memory locations during a first
6 mode of operation, and

7 allow sequential access to the contents of the memory locations
8 via a predetermined one of the memory locations during a second
9 mode of operation.

1 15. A method, comprising:
2 randomly accessing memory locations of a memory during a first mode
3 of operation, and
4 sequentially accessing the contents of the memory locations via a
5 predetermined one of the memory locations during a second mode of
6 operation.

1 16. The method of claim 15 wherein randomly accessing the memory
2 locations comprises:
3 accessing a first memory location having a first address; and
4 accessing a second memory location having a second address.

1 17. The method of claim 15 wherein sequentially accessing the memory
2 locations comprises:
3 reading first data from a first memory location;
4 shifting second data from a second memory location into the first memory
5 location; and
6 reading the second data from the first memory location.

1 18. The method of claim 15 wherein sequentially accessing the memory
2 locations comprises:
3 writing first data to a first memory location;
4 shifting the first data from the first memory location to a second memory
5 location; and
6 writing second data to the first memory location.

1 19. The method of claim 15 wherein randomly accessing the memory
2 locations comprises:
3 shifting the contents of each respective memory location to a respective next
4 memory location a number of times; and
5 accessing a predetermined one of the memory locations after a
6 predetermined one of the shifts.

- 1 20. The method of claim 15 wherein randomly accessing the memory
- 2 locations comprises:
- 3 shifting the contents of each of n respective memory locations to a respective
- 4 next one of the n memory locations n times; and
- 5 accessing a predetermined one of the n memory locations after a
- 6 predetermined one of the n shifts.